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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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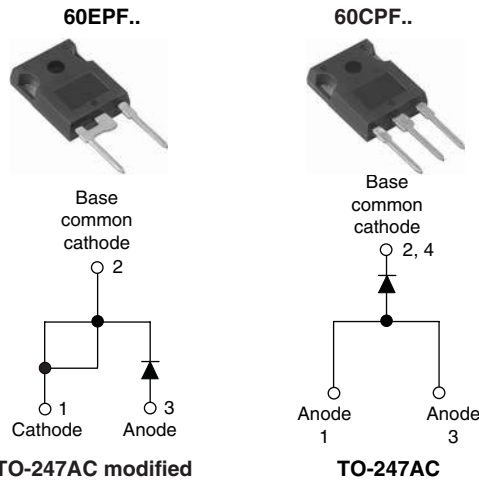
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Fast Soft Recovery Rectifier Diode, 60 A



FEATURES/DESCRIPTION

The 60EPF..PbF and 60CPF..PbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.



RoHS*
COMPLIANT

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level and lead (Pb)-free.

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

PRODUCT SUMMARY

V_F at 30 A	< 1.2 V
t_{rr}	95 ns
V_{RRM}	1000/1200 V

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		1000/1200	V
$I_{F(AV)}$	Sinusoidal waveform	60	A
I_{FSM}		700	
t_{rr}	1 A, - 100 A/ μ s	95	ns
V_F	30 A, $T_J = 25^\circ\text{C}$	1.2	V
T_J	Range	- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 $^\circ\text{C}$ mA
60EPF10PbF, 60CPF10PbF	1000	1100	8
60EPF12PbF, 60CPF12PbF	1200	1300	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 103^\circ\text{C}$, 180 $^\circ$ conduction half sine wave	60	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	700	
		10 ms sine pulse, no voltage reapplied	830	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	2450	A^2s
		10 ms sine pulse, no voltage reapplied	3460	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	34 600	$\text{A}^2\sqrt{\text{s}}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

60EPF..PbF, 60CPF..PbF Soft Recovery Series

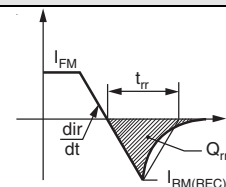


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Fast Soft Recovery
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	60 A, $T_J = 25\text{ }^\circ\text{C}$		1.4	V
Forward slope resistance	r_t	$T_J = 125\text{ }^\circ\text{C}$		4.6	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$			0.9	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		8	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 60 Apk 25 A/ μs 25 $^\circ\text{C}$	480	ns
Reverse recovery current	I_{rr}		8	A
Reverse recovery charge	Q_{rr}		2.7	μC
Snap factor	S		0.6	



THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 40 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.4	$^\circ\text{C/W}$
Maximum thermal resistance, junction to ambient	R_{thJA}		40	
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AC modified (JEDEC)	60EPF10	
			60EPF12	
		Case style TO-247AC	60CPF10	
			60CPF12	



60EPF..PbF, 60CPF..PbF Soft Recovery Series

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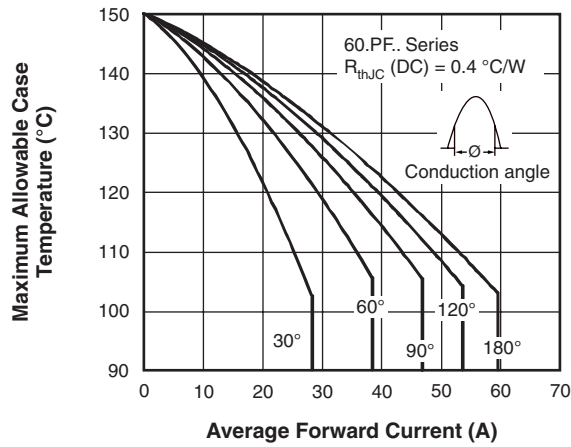


Fig. 1 - Current Rating Characteristics

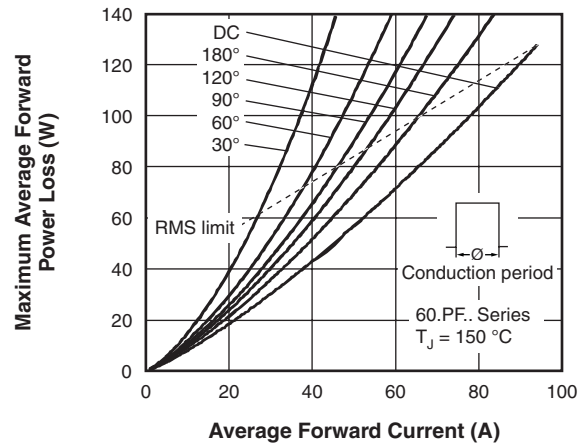


Fig. 4 - Forward Power Loss Characteristics

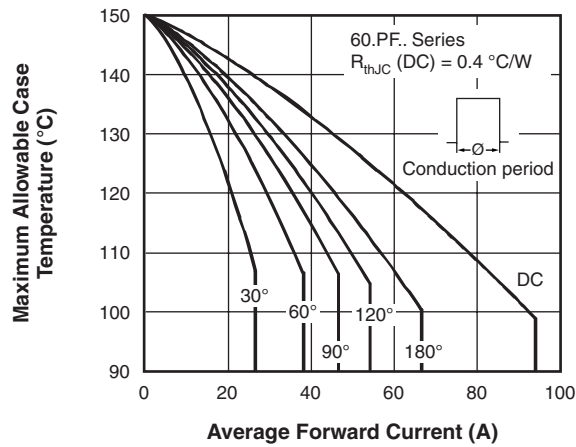


Fig. 2 - Current Rating Characteristics

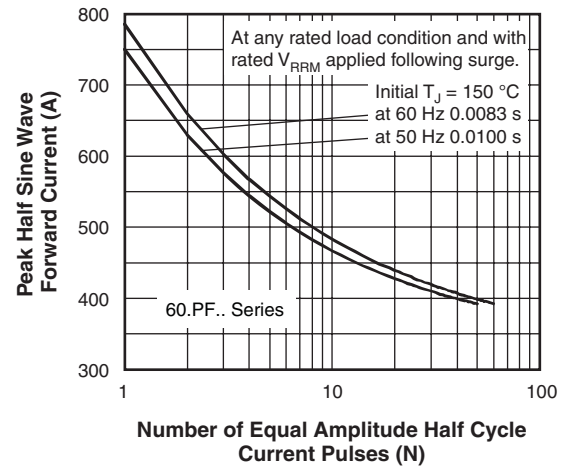


Fig. 5 - Maximum Non-Repetitive Surge Current

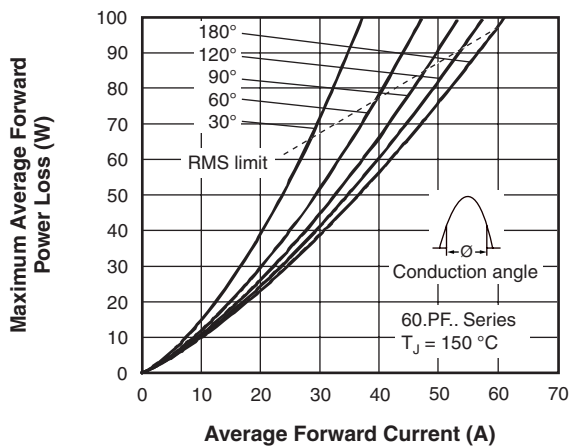


Fig. 3 - Forward Power Loss Characteristics

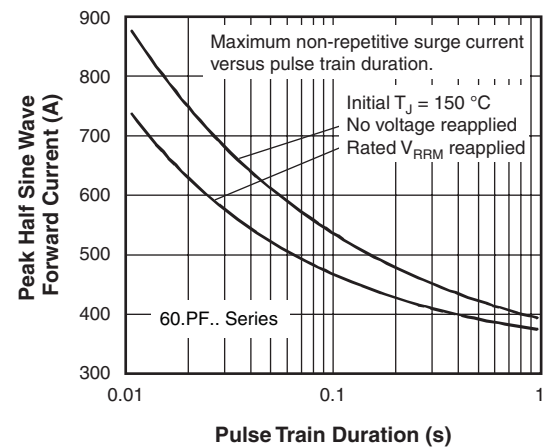


Fig. 6 - Maximum Non-Repetitive Surge Current

60EPF..PbF, 60CPF..PbF Soft Recovery Series



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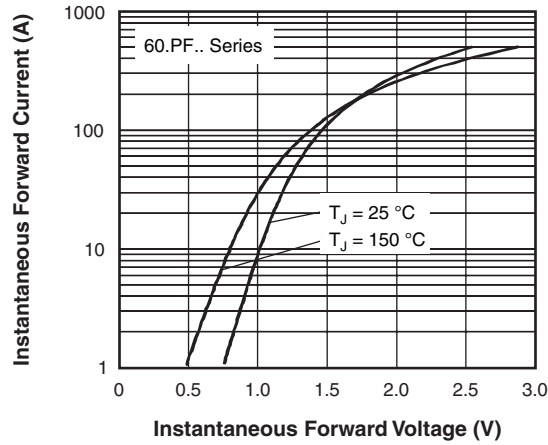


Fig. 7 - Forward Voltage Drop Characteristics

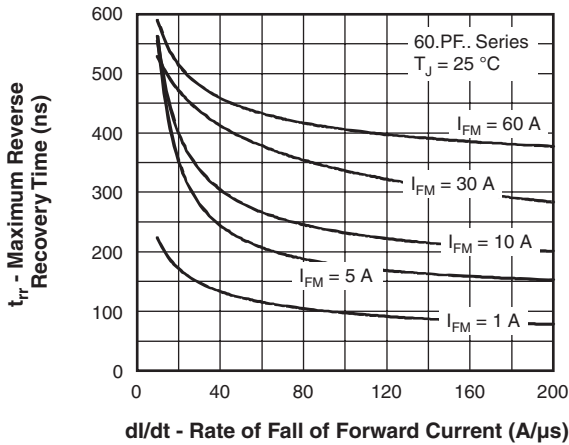


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ °C}$

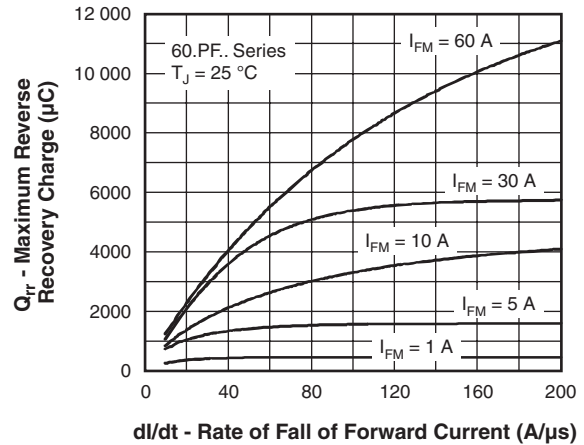


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ °C}$

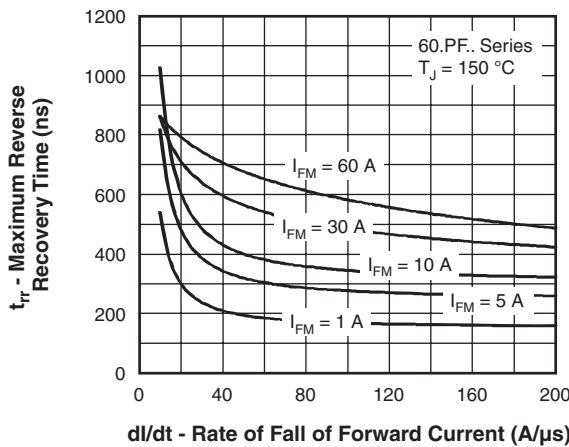


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ °C}$

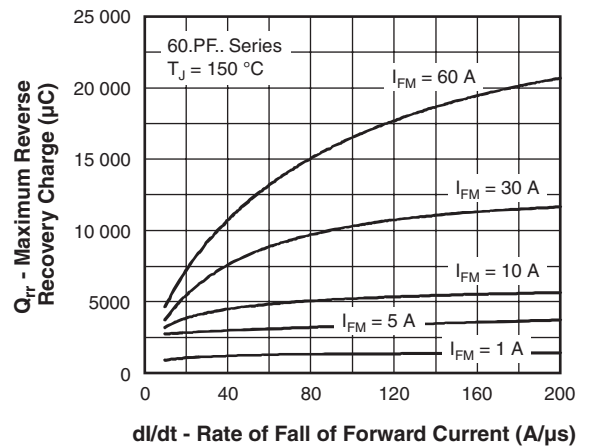


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ °C}$



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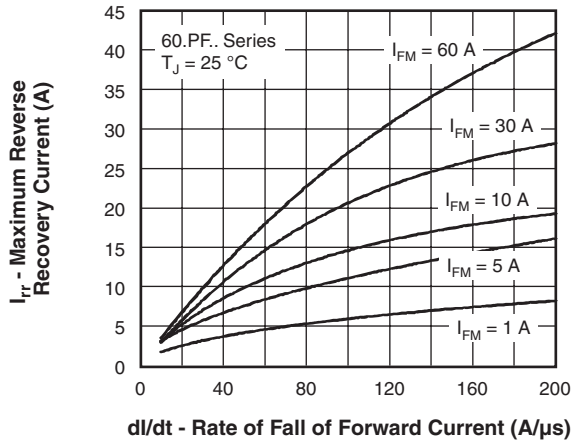


Fig. 12 - Recovery Current Characteristics, $T_J = 25\text{ }^\circ\text{C}$

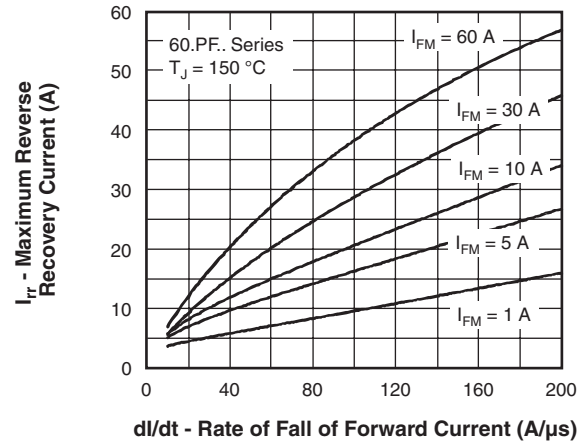


Fig. 13 - Recovery Current Characteristics, $T_J = 150\text{ }^\circ\text{C}$

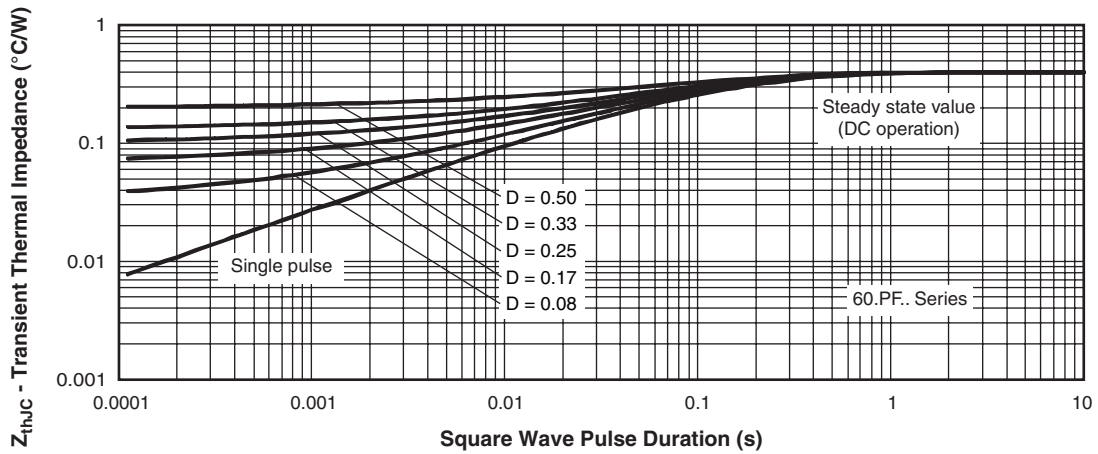


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

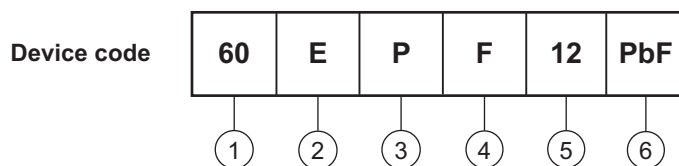
60EPF..PbF, 60CPF..PbF Soft Recovery Series



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ORDERING INFORMATION TABLE



- 1** - Current rating (60 = 60 A)
- 2** - Circuit configuration:
 - E = Single diode
 - C = Single diode, 3 pins
- 3** - Package:
 - P = TO-247AC modified
- 4** - Type of silicon:
 - F = Fast recovery
- 5** - Voltage code x 100 = V_{RRM}
- 6** -
 - None = Standard production
 - PbF = Lead (Pb)-free

10 = 1000 V 12 = 1200 V

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95001
Part marking information	http://www.vishay.com/doc?95006



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